

# SANYO Semiconductors DATA SHEET

# 2SC6098 — NPN Epitaxial Planar Silicon Transistor

# **High-Voltage Switching Applications**

# **Applications**

• DC / DC converter, relay drivers, lamp drivers, motor drivers, inverter.

#### **Features**

- · Adoption of FBET, MBIT process.
- · High current capacitance.
- · Low collector-to-emitter saturation voltage.
- · High-speed switching.
- · High allowable power dissipation.

### **Specifications**

#### **Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		120	V
Collector-to-Emitter Voltage	VCES		120	V
Collector-to-Emitter Voltage	VCEO		80	V
Emitter-to-Base Voltage	VEBO		6.5	V
Collector Current	IC		2.5	Α
Collector Current (Pulse)	lCP		4	Α
Base Current	IB		500	mA
Collector Dissipation	Po		0.8	W
	PC	Tc=25°C	15	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =70V, I <sub>E</sub> =0A			1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1	μΑ
DC Current Gain	hFE	V <sub>CE</sub> =5V, I <sub>C</sub> =100mA	300		600	

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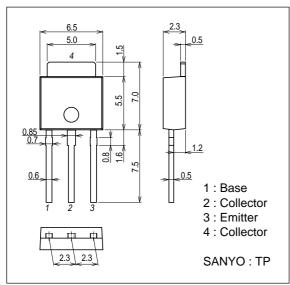
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA		350		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		14		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)1	IC=1A, IB=50mA		110	165	mV
	VCE(sat)2	IC=1A, IB=100mA		100	150	mV
Base-to-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	I <sub>C</sub> =1A, I <sub>B</sub> =100mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0A	120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CES	I <sub>C</sub> =100μA, R <sub>BE</sub> =0Ω	120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	80			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0A	6.5			V
Turn-ON Time	ton	See specified Test Circuit.		40		ns
Storage Time	tstg	See specified Test Circuit.		920		ns
Fall Time	tf	See specified Test Circuit.		32		ns

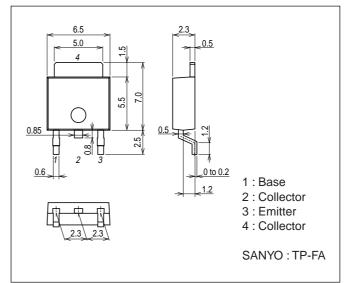
# **Package Dimensions**

unit : mm 7518-003

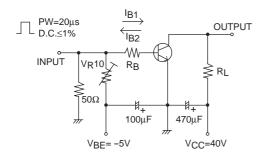


# **Package Dimensions**

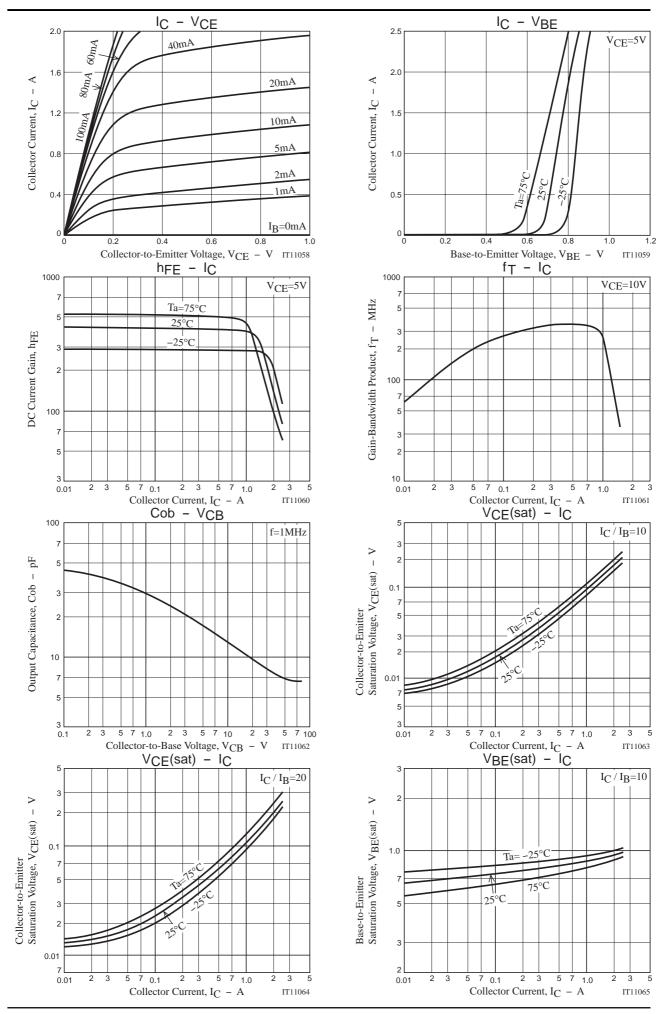
unit : mm 7003-003



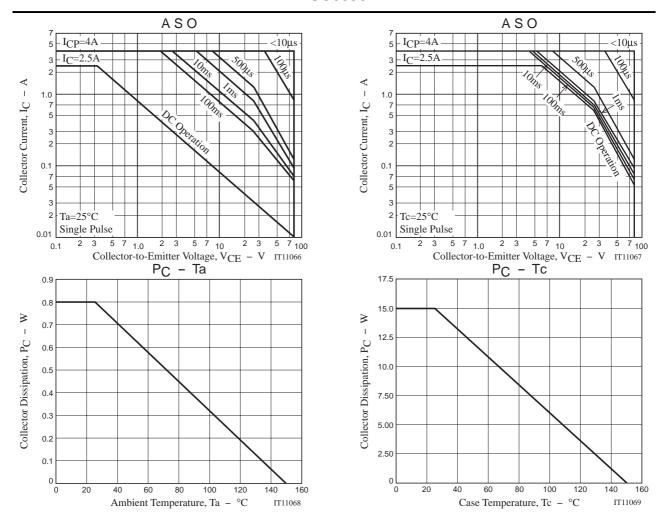
# **Switching Time Test Circuit**



$$10I_{B1} = -10I_{B2} = I_{C} = 0.5A$$



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